

NVC6S5A354PLZ

Advance Information

Power MOSFET

-60V, 100mΩ, -4A, P-Channel



ON Semiconductor®

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This Power MOSFET is produced using ON Semiconductor's trench technology, which is specifically designed to minimize gate charge and low on resistance. This device is suitable for applications with low gate charge driving or low on resistance requirements.

Features

- 4V drive
- High ESD protection
- Low On-Resistance
- Pb-Free, Halogen Free and RoHS compliance

Typical Applications

- Reverse Battery Protection
- High Side Load Switch

SPECIFICATIONS

ABSOLUTE MAXIMUM RATING at Ta = 25°C (Note 1)

Parameter	Symbol	Value	Unit
Drain to Source Voltage	V _{DSS}	-60	V
Gate to Source Voltage	V _{GSS}	±20	V
Drain Current (DC) (Note 2)	I _D	-4	A
Drain Current (DC) (Note 3)		-3	A
Drain Current (Pulse) PW ≤ 10μs, duty cycle ≤ 1%	I _{DP}	-16	A
Power Dissipation Ta=25°C(Note 2)	P _D	1.9	W
Power Dissipation Ta=25°C(Note 3)		0.9	W
Junction Temperature and Storage Temperature	T _J , T _{stg}	-55 to +175	°C

Note 1 : Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit
Junction to Ambient	R _{θJA}	78.1	°C/W
		160	°C/W

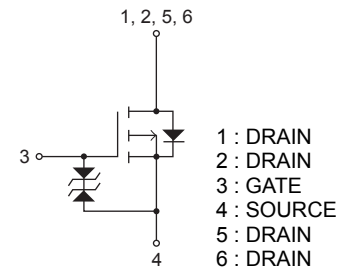
Note 2 : Surface mounted on ceramic substrate(1500mm² × 0.8mm).

Note 3 : Surface mounted on FR4 board using a 92mm², 1 oz. Cu pad.

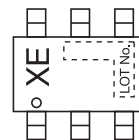
This document contains information on a new product. Specifications and information herein are subject to change without notice.

V _{DSS}	R _{DS(on)} Max	I _D Max
-60V	100mΩ@ -10V	-4A
	135mΩ@ -4.5V	
	145mΩ@ -4.0V	

ELECTRICAL CONNECTION P-Channel



MARKING



ORDERING INFORMATION

See detailed ordering and shipping information on page 6 of this data sheet.

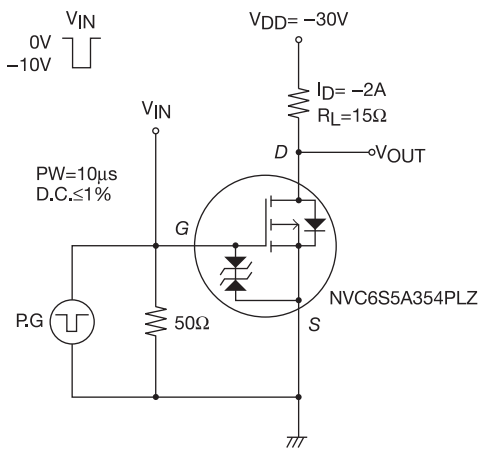
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ELECTRICAL CHARACTERISTICS at Ta = 25°C (Note 4)

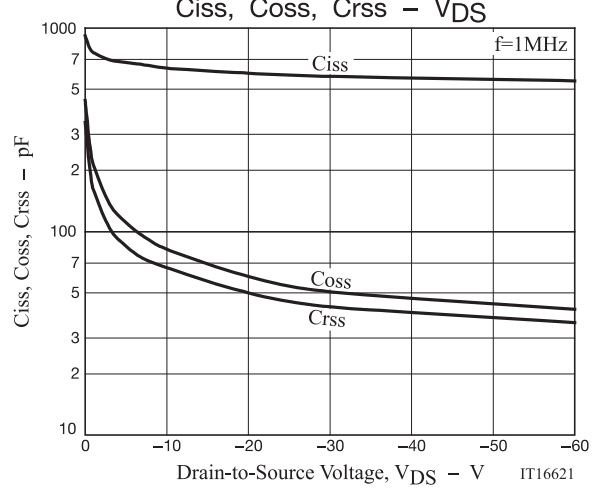
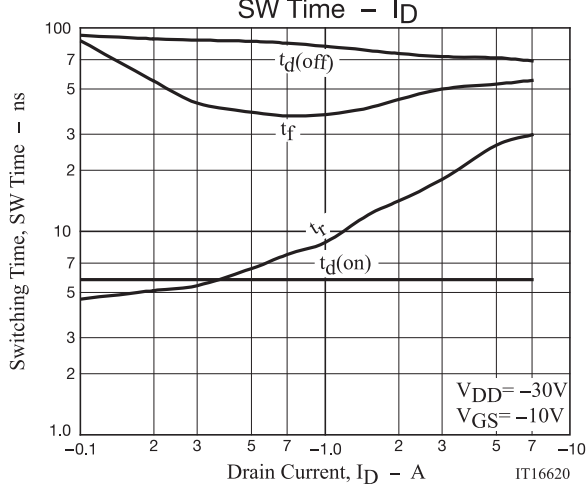
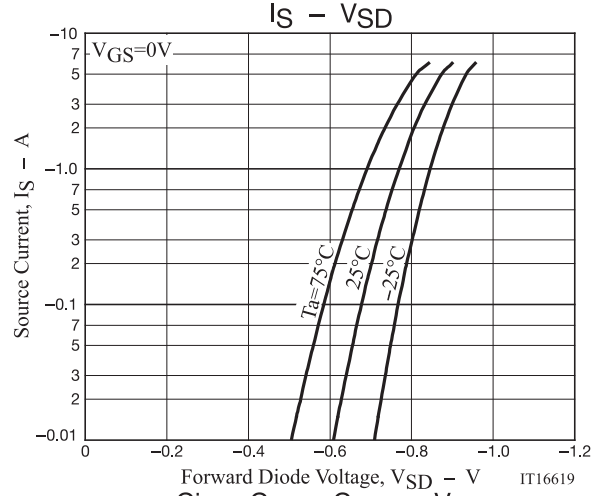
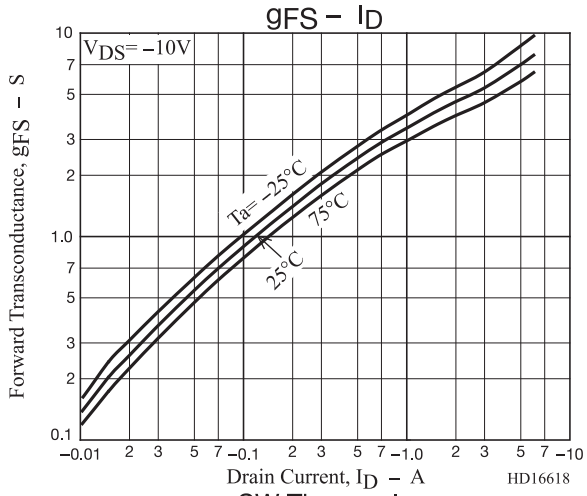
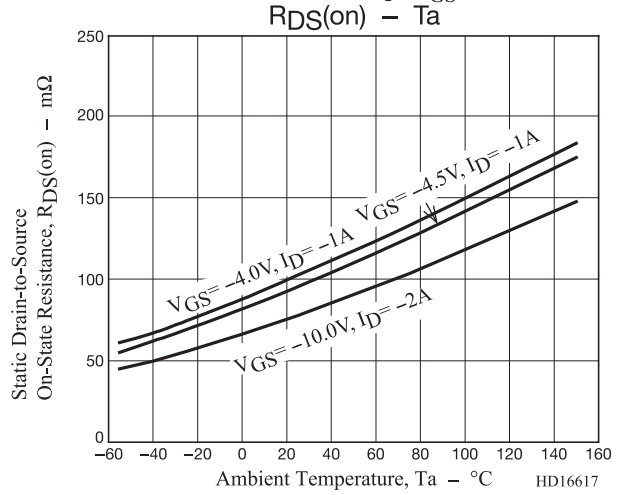
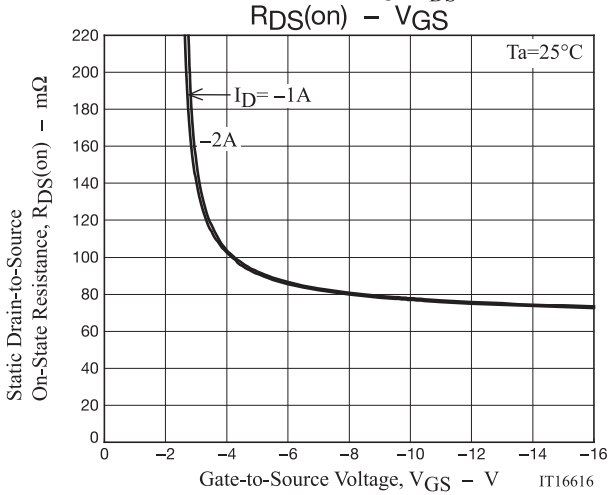
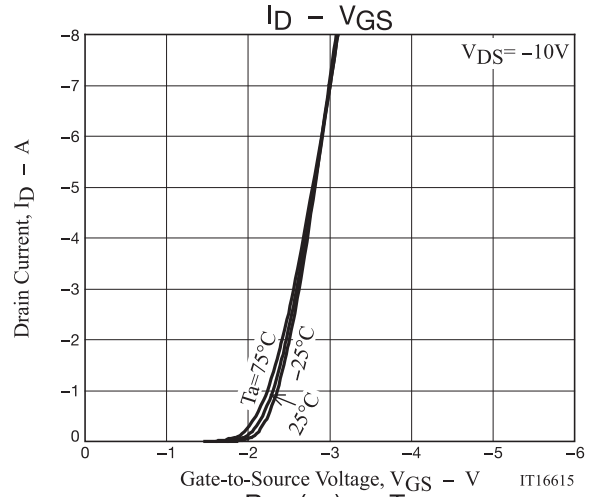
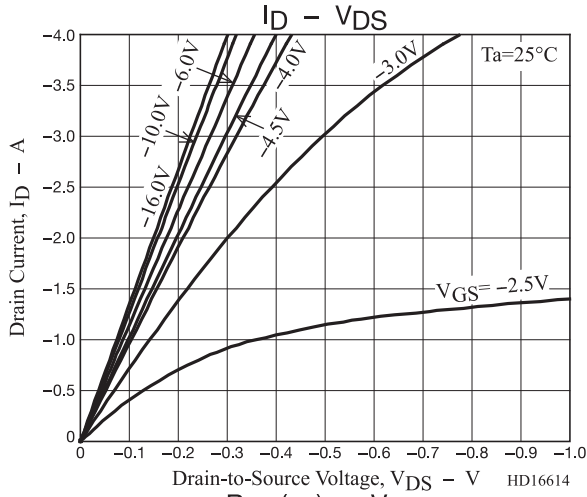
Parameter	Symbol	Conditions	Value			Unit
			min	typ	max	
Drain to Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-60			V
Zero-Gate Voltage Drain Current	IDSS	VDS=-60V, VGS=0V			-1	μA
Gate to Source Leakage Current	IGSS	VGS=±16V, VDS=0V			±10	μA
Gate Threshold Voltage	VGS(th)	VDS=-10V, ID=-1mA	-1.2		-2.6	V
Forward Transconductance	gFS	VDS=-10V, ID=-2A		4.8		S
Static Drain to Source On-State Resistance	RDS(on)	ID=-2A, VGS=-10V		77	100	mΩ
		ID=-1A, VGS=-4.5V		96	135	mΩ
		ID=-1A, VGS=-4V		103	145	mΩ
Input Capacitance	Ciss	VDS=-20V, f=1MHz		600		pF
Output Capacitance	Coss			60		pF
Reverse Transfer Capacitance	Crss			50		pF
Turn-ON Delay Time	t _{d(on)}		See Fig.1		5.8	
Rise Time	t _r			12		ns
Turn-OFF Delay Time	t _{d(off)}			78		ns
Fall Time	t _f			40		ns
Total Gate Charge	Qg	VDS=-30V, VGS=-10V, ID=-4A		14		nC
Gate to Source Charge	Qgs			1.6		nC
Gate to Drain "Miller" Charge	Qgd			3.4		nC
Forward Diode Voltage	VSD		IS=-4A, VGS=0V		-0.84	-1.2

Note 4 : Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

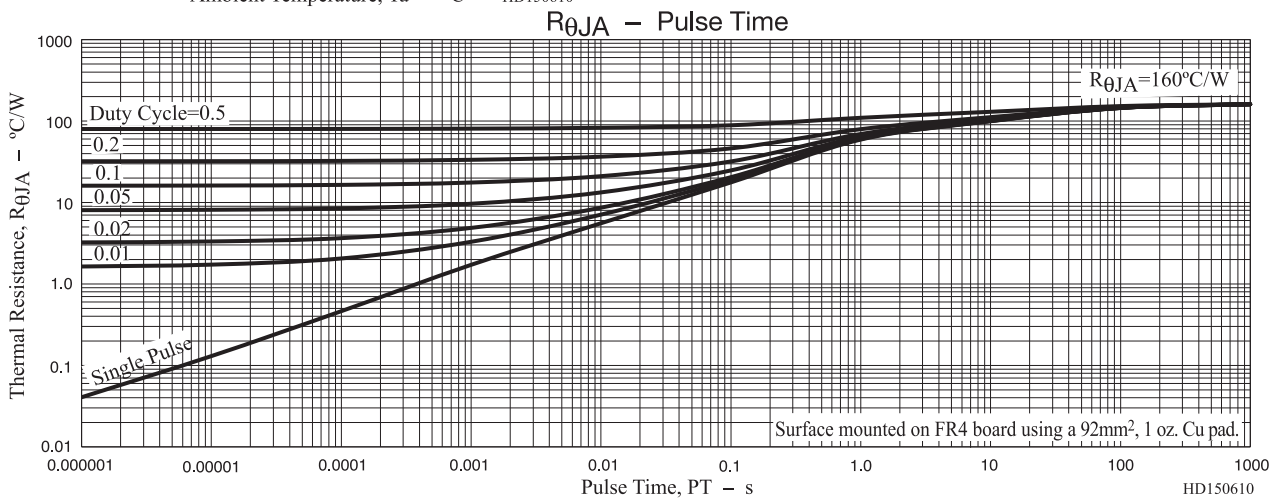
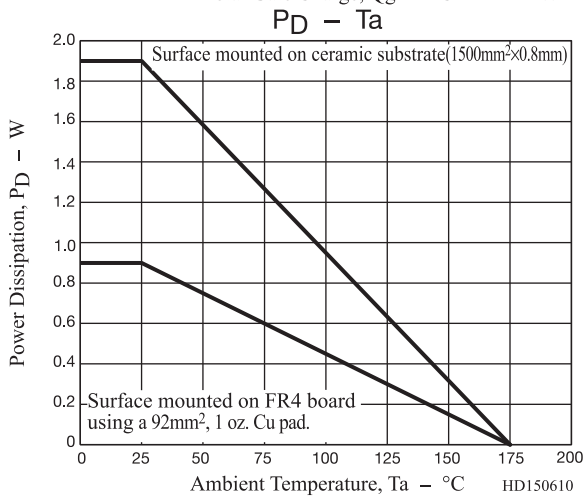
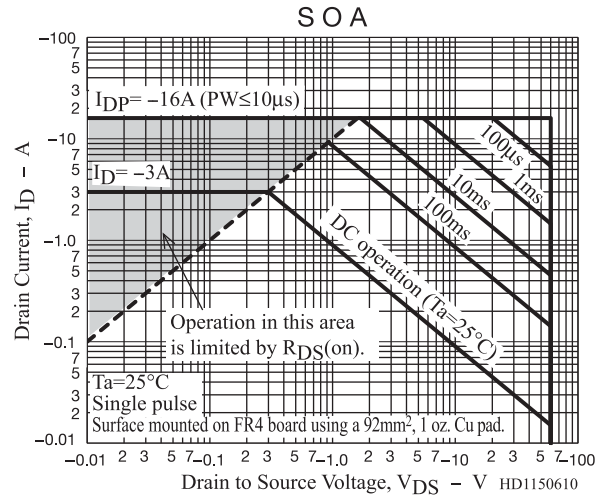
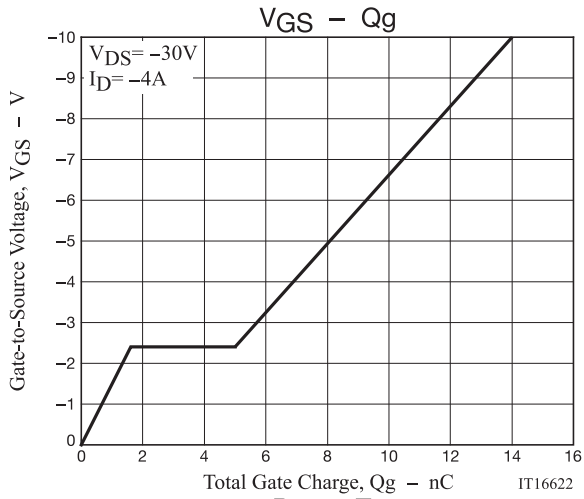
Fig.1 Switching Time Test Circuit



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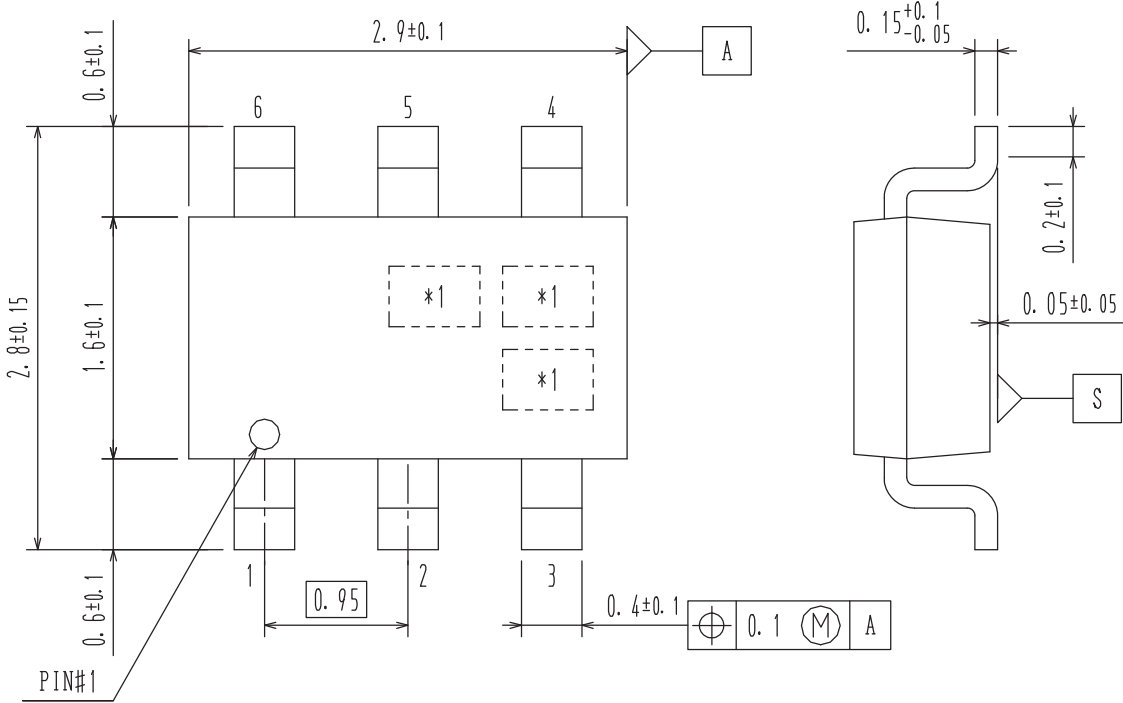
PACKAGE DIMENSIONS

unit : mm

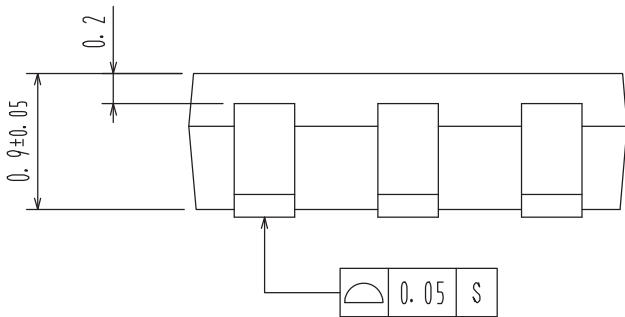
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CASE 318BD

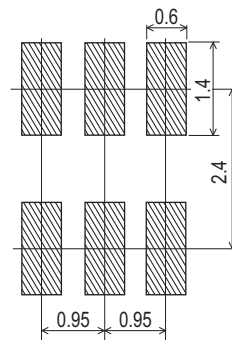
ISSUE O



*1: Lot indication



Recommended Soldering Footprint



- 1 : DRAIN
- 2 : DRAIN
- 3 : GATE
- 4 : SOURCE
- 5 : DRAIN
- 6 : DRAIN

NVC6S5A354PLZ

ORDERING INFORMATION

Device	Marking	Package	Shipping (Qty / Packing)
NVC6S5A354PLZT1G	XE	CPH6 (Pb-Free / Halogen Free)	3,000 / Tape & Reel

† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. http://www.onsemi.com/pub_link/Collateral/BRD8011-D.PDF

Note on usage : Since the NVC6S5A354PLZ is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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